NSN 5961-01-397-0234

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-397-0234 **Inclosure Material:** Metal **Overall Length:** 0.830 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Overall Width Across Flats:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 600.0 reverse voltage, peak **Current Rating Per Characteristic:** 12.00 amperes forward current, average **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Special Features:** Contains beryllium oxide - handle and dispose iaw hazmat procedures **Precious Material And Location:** Terminals and mtg stud gold or terminals and mtg stud silver **Precious Material:** Gold or silver **Terminal Type And Quantity:** 1 tab, solder lug and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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